In the claims:

- of a photoresist mask, comprising the steps of obtaining in a scanning electron microscope a video signal of a bottom of an opening of a photoresist mask; and comparing values of the video signal in different points of an image which contains the opening to be controlled; and making the conclusion about a presence or absence of photoresist based on the compared values of the video signal in different points of the video signal in different points of the image which contains the opening.
- 2. (Currently amended) A method as defined in claim 1A method of making a conclusion about a presence or absence of photoresist in openings of a photoresist mask, comprising the steps of obtaining in a scanning electron microscope a video signal of a bottom of an opening of a photoresist mask; and comparing values of the video signal in different points of an image which contains the opening, wherein said comparing includes selecting a portion of a field of vision outside of an image of the opening; determining a mean value of the video signal and a mean square amplitude of noise on the selected portion; subdividing the image of the bottom of the

opening into fragments; repeating calculations of a mean signal in each fragment; calculating paired differences of average values of the signal; selecting those paired differences which exceed a threshold; and making a conclusion about a presence or absence of non-remotenon-removed photoresist with determination of borders of the islands.

- 3. (Original) A method as defined in claim 2, wherein the selecting the portion of the field of vision outside of the image of the opening is performed with a size of the portion not less than 10 x 10 pixels.
- 4. (Original) A method as defined in claim 2, wherein determining the mean value of the video signal on the selected portion is performed in accordance with the formula:

$$S_{AVE} = \frac{\sum_{i=1}^{n} S(i)}{n}$$

wherein i is a number of pixel, n is a number of pixels involved in the calculation of the mean signal, and S(i) is an individual value of the video signal.

5. (Original) A method as defined in claim 2, wherein the determining the mean square amplitude of noises N is performed in accordance with the formula:

$$N = \frac{1}{\sqrt{n}} \sqrt{\sum_{i=1}^{n} [S(i) - S_{AVE}]^2}$$

- 6. (Original) A method as defined in claim 2, wherein the subdividing of the image of the bottom of the opening in the fragment is performed with the selection of the fragments sizes m x m, wherein m is 3-10, and a number of pixels in the fragment is m².
- 7. (Original) A method as defined in claim 2, wherein the calculating of a mean value of the video signal in the fragment is performed in accordance with the formula:

$$SF(1) = \frac{1}{m^2} \sum_{j=1}^{m^2} S(j)$$

8. (Original) A method as defined in claim 2, wherein the repeated calculating a mean signal in each fragment is performed until all fragments cover the image of the bottom of the opening.

9. (Original) A method as defined in claim 2, making a conclusion about presence of islands of non-remote resist by comparison of the paired differences with an expected fluctuations of background

$$FF = 3\frac{N}{m}$$
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10. (Original) A method as defined in claim 1; and further comprising the image obtained in the scan and electron microscope obtaining at a reduced accelerating voltage, in order to increase sensitivity of determination of the non-removed photoresist layer.